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# 2SK974(L), 2SK974(S)

Silicon N-Channel MOS FET

## HITACHI

November 1996

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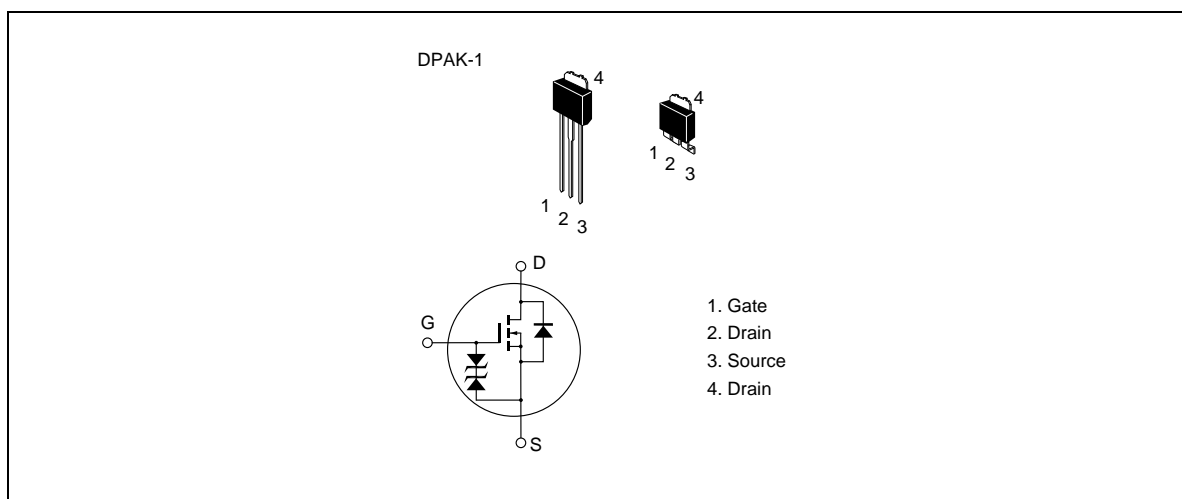
### Application

High speed power switching

### Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
  - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

### Outline



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## 2SK974(L), 2SK974(S)

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### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	60	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	$I_D$	3	A
Drain peak current	$I_{D(peak)}^{*1}$	12	A
Body to drain diode reverse drain current	$I_{DR}$	3	A
Channel dissipation	$Pch^{*2}$	20	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$   
2. Value at  $T_c = 25^\circ C$

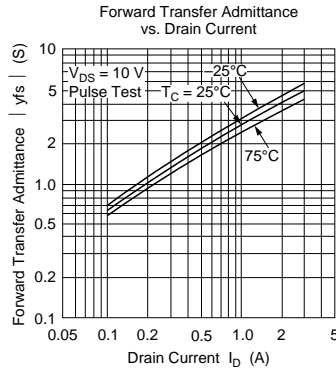
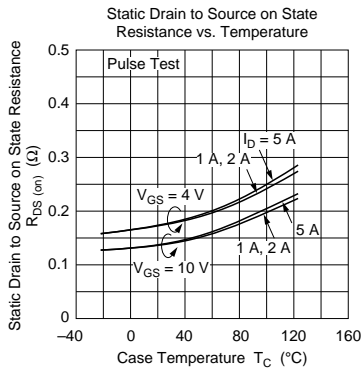
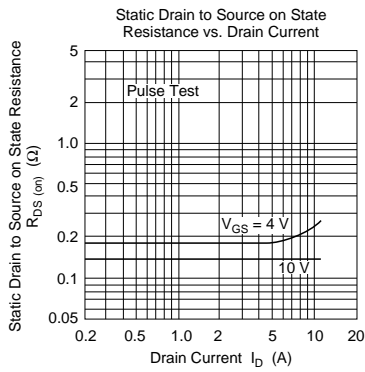
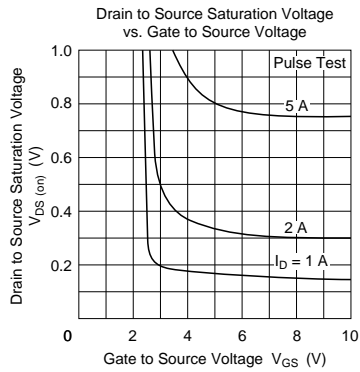
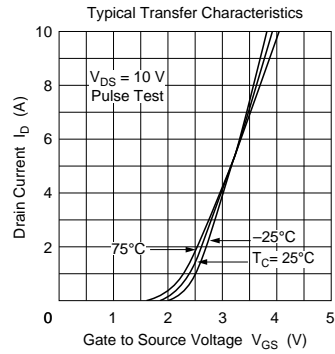
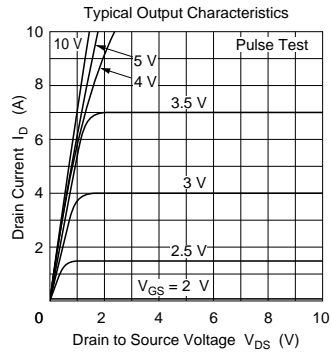
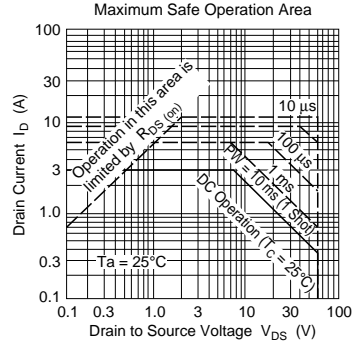
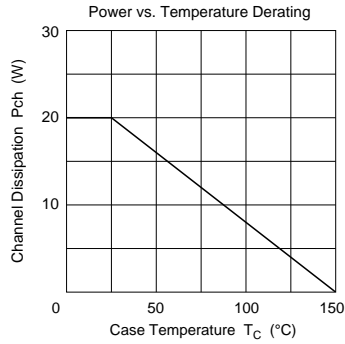
## 2SK974(L), 2SK974(S)

### Electrical Characteristics (Ta = 25°C)

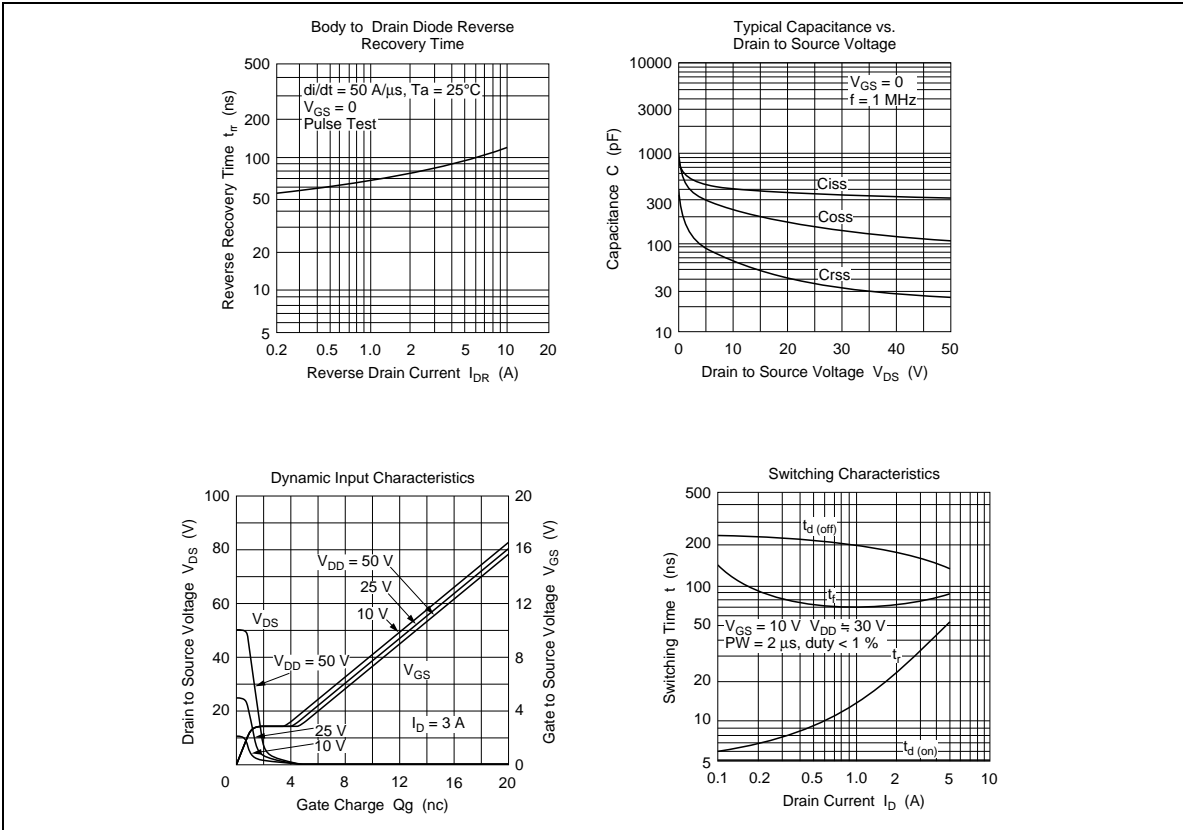
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	±10	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	100	μA	$V_{DS} = 50 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.15	0.18	Ω	$I_D = 2 \text{ A}, V_{GS} = 10 \text{ V}^{*1}$
			0.20	0.25	Ω	$I_D = 2 \text{ A}, V_{GS} = 4 \text{ V}^{*1}$
Forward transfer admittance	yfs	2.4	4.0	—	S	$I_D = 2 \text{ A}, V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	Ciss	—	400	—	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$ $f = 1 \text{ MHz}$
Output capacitance	Coss	—	230	—	pF	
Reverse transfer capacitance	Crss	—	60	—	pF	
Turn-on delay time	$t_{d(on)}$	—	5	—	ns	$I_D = 2 \text{ A}, V_{GS} = 10 \text{ V},$ $R_L = 15 \Omega$
Rise time	$t_r$	—	25	—	ns	
Turn-off delay time	$t_{d(off)}$	—	180	—	ns	
Fall time	$t_f$	—	75	—	ns	
Body to drain diode forward voltage	$V_{DF}$	—	0.9	—	V	$I_F = 3 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	trr	—	85	—	ns	$I_F = 3 \text{ A}, V_{GS} = 0,$ $di_F/dt = 50 \text{ A}/\mu\text{s}$

Note 1. Pulse test

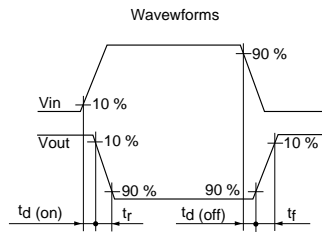
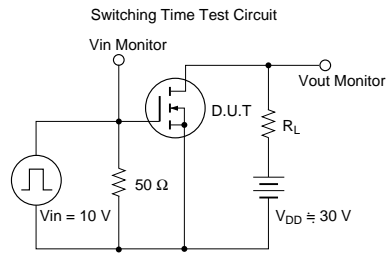
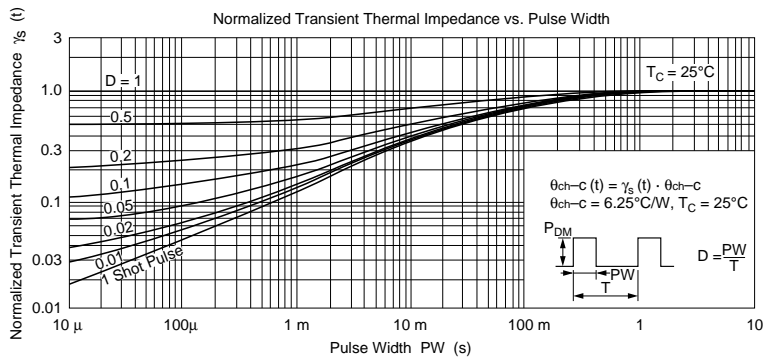
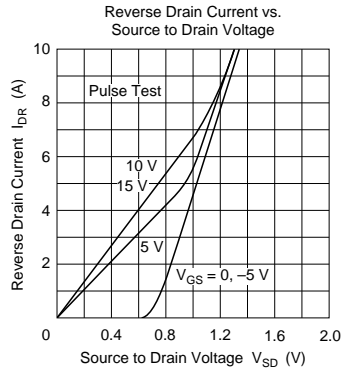
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